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A 45nm CMOS Neuromorphic Chip with a Scalable Architecture for Learning in Networks of Spiking Neurons

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Abstract—Efforts to achieve the long-standing dream of realizing scalable learning algorithms for networks of spiking neurons in silicon have been hampered by (a) the limited scalability of analog neuron circuits; (b) the enormous area overhead of learning circuits, which *grows with the number of synapses*; and (c) the need to implement all inter-neuron communication via off-chip address-events. In this work, a new architecture is proposed to overcome these challenges by combining innovations in computation, memory, and communication, respectively, to leverage (a) robust digital neuron circuits; (b) novel transposable SRAM arrays that share learning circuits, which *grow only with the number of neurons*; and (c) crossbar fan-out for efficient on-chip inter-neuron communication. Through tight integration of memory (synapses) and computation (neurons), a highly configurable chip comprising 256 neurons and 64K binary synapses with on-chip learning based on spike-timing dependent plasticity is demonstrated in 45nm SOI-CMOS. Near-threshold, event-driven operation at 0.53V is demonstrated to maximize power efficiency for real-time pattern classification, recognition, and associative memory tasks. Future scalable systems built from the foundation provided by this work will open up possibilities for ubiquitous ultra-dense, ultra-low power brain-like cognitive computers.

I. INTRODUCTION

In recent years, the development of large-scale networks with spiking neurons [1] and adaptive synapses based on spike-timing dependent plasticity (STDP) [2] has suggested new avenues of exploration for brain-like cognitive computing. A massively scaled example of this work is described in [3], which reports a cortical simulation at the scale of a cat cortex (10^9 neurons and 10^{13} synapses) using supercomputers. When compared to a brain that consumes 20W and occupies just 2L, the memory, computation, communication, power, and space resources needed for such a software simulation are tremendous. Consequently, there is an enormous opportunity for efficient, dedicated VLSI hardware that moves beyond prevalent von Neumann architectures to ultimately enable true large mammalian brain-scale networks (10^{10} neurons and 10^{14} synapses) with extremely low power consumption ($< 1\text{kW}$) and volume ($< 2\text{L}$) for ubiquitous deployment. Achieving this ambitious goal will demand a combination of advances in architectures designed to exploit spiking network properties coupled with exploitation of continued CMOS scaling.

A number of previous approaches implementing networks of spiking neurons in silicon [4][5][6] utilize analog circuit techniques (e.g. capacitor charge storage) and off-chip implementations of synapse plasticity, which limits portability to advanced technology nodes. On-chip synaptic learning was demonstrated with binary synapses in [7], but the number of synapses integrated on chip was limited as STDP circuitry was needed for *each* synapse element.

In this paper, we propose a scalable integrated circuit platform for large-scale networks of spiking neurons. We under-

took a digital circuit approach, not only for scalability, inherent noise rejection, and robustness to variability, but also for reconfigurability, which enables our chip to serve as a general vehicle to support multiple learning algorithms and tasks. Tailored towards cognitive tasks such as pattern classification and object recognition, the architecture of the neuromorphic chip implemented here leverages a processor-in-memory approach to enable efficient communication between neurons and synapses. Efficient on-chip learning is enabled by a novel transposable synapse crossbar array to perform synapse weight updates in both row (post-synaptic) and column (pre-synaptic) directions in a single step. Such an organization allows sharing of the synapse learning circuitry across axons (rows) and dendrites (columns) at the crossbar periphery, which dramatically improves synaptic density. With an end target of a large-scale brain network operating in “real-time” ($\sim\text{ms}$ time steps), low power consumption was achieved by the use of near-threshold circuits and an event-driven synchronous design.

Embodying the above unique solutions encompassing computation, memory, and communication, an integrated neuromorphic chip was fabricated in 45nm SOI-CMOS to demonstrate auto-associative learning and spatio-temporally sparse pattern recognition [8][9]. Additionally, three chip variants were designed and successfully demonstrated to precisely understand (1) density of reconfigurable versus customized neurons, (2) learning performance of chips with single-bit versus multi-bit synapses, and (3) power optimization by transistor threshold voltage adjustment.

II. CHIP DESIGN FOR NETWORKS OF SPIKING NEURONS

The essential dynamics of neurons and synapses in networks of spiking neurons is first provided, and we describe the chip design which efficiently implements those key features.

A. Networks of spiking neurons

A network of spiking neurons is comprised of neuron processing elements connected through synapse memory elements – both akin to the basic building blocks of the brain. Neurons communicate through binary messages called spikes, typically produced at 1-10 Hz. A spike is sent on a generating neuron’s axon to the dendrites of other neurons. The point of contact between an axon and dendrite is the synapse, which has a particular strength that determines the efficacy of a spike from a source, pre-synaptic neuron, on a target, post-synaptic neuron. Each neuron has a membrane potential that changes with incoming spikes and decays over time due to a leak. If the membrane potential exceeds a threshold, the neuron generates its own spike and the membrane potential is reset. Each neuron can be excitatory or inhibitory. Spikes from excitatory neurons increase the membrane potential of post-synaptic neurons, while spikes from inhibitory neurons do the opposite.

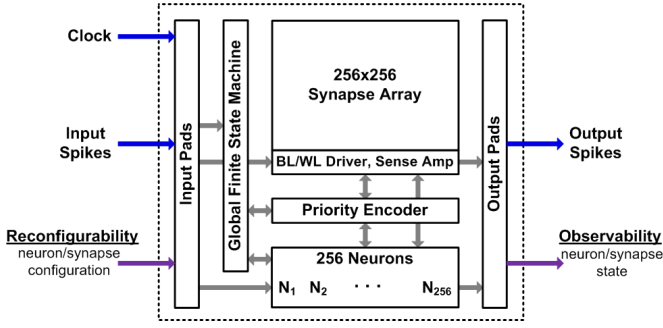


Fig. 1. Top-level block diagram of on-chip learning chip.

Networks of spiking neurons exhibit the ability to learn and adapt through the evolution of synapse weights. Such synaptic plasticity can be governed by time-dependent learning rules such as STDP, in which synapse weight changes depending on the order and distance in time between the spikes of source and target neurons. When a neuron fires, all incoming dendritic and outgoing axonal synapses must be updated.

The neuromorphic chip implemented in this work (Fig. 1), a scalable building block for large-scale networks of spiking neurons, integrates 256 neurons with 256x256 binary synapses to represent a fully recurrent network. In each time step, neurons that have exceeded their firing threshold generate spikes, which triggers synaptic integration in all target neurons as well as synapse weight updates based on the specified learning rule. Input spikes to the system can represent external stimuli (e.g. an input pattern) while generated spikes can represent output activity (e.g. recognition of a given pattern).

B. Transposable SRAM Synapse Crossbar Array

An $N \times N$ crossbar structure can effectively represent a system of N neurons and N^2 possible synaptic connections between them. Each row of the crossbar represents a neuron's axon and each column represents a neuron's dendrite. In stark contrast to traditional VLSI circuits, a large fan-in and fan-out can thus be efficiently realized as neuronal computations and synaptic updates can be parallelized, since an entire row or column of the crossbar can be operated upon simultaneously. To efficiently implement time-dependent learning rules, both row and column accesses are important, since pre-synaptic row and post-synaptic column updates are required. Conventional memory arrays are accessed only in rows, and column-based access would require inefficient serial row operations. Instead, this shortcoming is addressed in this work by a transposable SRAM cell (Fig. 2) to store synapse weights, which enables single-cycle write and read access in both row and

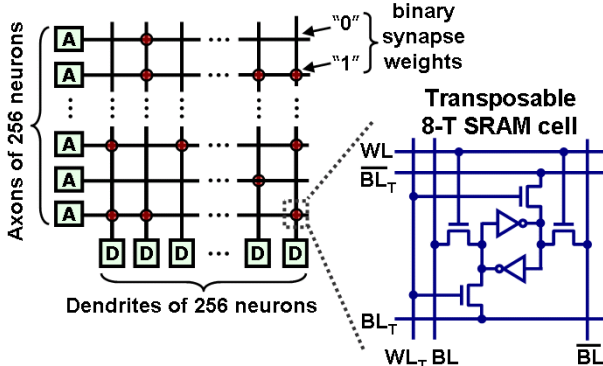


Fig. 2. Synapse array with transposable SRAM cells.

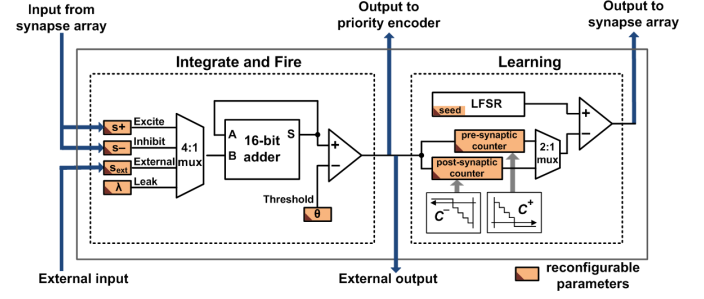


Fig. 3. Digital CMOS neuron with reconfigurability.

column directions to significantly enhance on-chip learning performance. The transposable SRAM cell uses 8 transistors, adding two access transistors connected to word and bit lines in transposed orientations to a standard 6T design. The cell area is $1.6\mu\text{m}^2$ in 45nm and is fully compatible with logic ground rules to enable excellent low voltage yield.

While much previous work focuses on analog synapse weights, this work utilizes binary synapses for optimal density, where each synapse is represented by a single memory cell. Instead of increasing or decreasing analog values, these binary weights are probabilistically set to '1' or '0' depending on the learning rule [10].

The synapse crossbar memory is implemented by a 256x256 array of transposable SRAM cells. To maximize array efficiency and timing margins, the 256 cells in either orientation are connected to a common bit line without any hierarchical structures. Read operations are performed by a conventional differential-pair sense amplifier while cross-coupled keeper PFET devices ensure noise tolerance and robustness to leakage effects during the slow cycle times needed for real-time system performance. Yield analysis considering process corners and statistical process variation using Monte Carlo methods was conducted to ensure design robustness.

C. Digital CMOS Neuron Circuits

Each neuron implements locally reconfigurable integrate-and-fire function [1] and learning rules (Fig. 3). At a functional level, the neuron follows the equation: $V(t) = V(t-1) + s_+ n_+(t) - s_- n_-(t) - \lambda$ where V is the membrane potential, n_+ and n_- are the number of excitatory and inhibitory inputs received through "on" synapses, s_+ and s_- are input strength parameters and λ is a leak parameter. If $V(t)$ exceeds a threshold θ , a spike is generated and $V(t)$ is set to V_{reset} . The membrane potential and parameters are 8-bit digital values. The integrate-and-fire module utilizes a 16-bit adder to handle overflow under worst-case conditions and a digital comparator to evaluate the spiking threshold. A 4:1 mux reuses the adder to integrate inputs and leak at each time step.

The circuits needed to perform probabilistic synapse weight update via time-dependent learning rules are implemented within the neuron, which thus shares learning circuitry across axonal rows and dendritic columns of synapses. 8-bit time-keeping counters C^+ and C^- enable independent control of pre- and post-synaptic updates, respectively, by tracking the time elapsed since the last spiking event of each neuron. When a neuron spikes these counters are set to 8-bit parameters C_{set}^+ and C_{set}^- and decay by 3-bit parameters C_{decay}^+ and C_{decay}^- each time step. During a pre- (post-) synaptic update, the neuron will activate the crossbar's column (row) word line associated

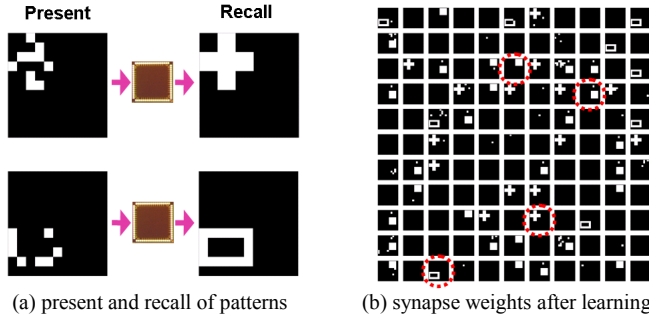


Fig. 6. The effect of learning in the first system is shown. (a) After on-chip learning, the system is presented with an incomplete image (via input spikes) and a complete image is recalled (via output spikes). (b) The weights of synapses connecting different layers of excitatory neurons, after learning, are shown. Examples of the trained patterns are marked with circles. (For both spikes and synapses, white represents ‘1’, and black represents ‘0’.)

time step. Our hardware implementation of this network had a capacity of 0.047 patterns per neuron when the system was used with binary synapses, and this improved to 0.109 in the 4-bit synapse variant, which can be compared to the Hopfield networks theoretical capacity of 0.139.

Measured hardware successfully performed the learning tasks described above down to 0.53V for the base, slim neuron, and 4-bit synapse variants and 0.55V for the low leakage variant (due to increased σV_t of the low leakage devices). For massively parallel systems, such near-threshold operation has been shown to provide optimal power efficiency [11], which will be critical to realizing an ultimate brain-scale system. As shown in Fig. 7, the low-leakage variant consumes a total leakage power of 0.5mW at 0.55V. When there is no spiking activity, this leakage power could be reduced by data-retention power-gating as long as the neuron potential and synapse values are maintained. The measured minimum retention voltage for the low-leakage variant is 0.25V, which achieves a leakage power of 26 μ W – a 20X reduction from 0.55V.

An overall comparison of the area, power, and learning performance of the four design variants is shown in Fig. 8. While application-specific designs provide optimal density, ultra-low-leakage devices provide optimal power, and multi-bit synapses provide optimal learning speed, each design carries significant tradeoffs and must be carefully considered when scaling to a large-scale system.

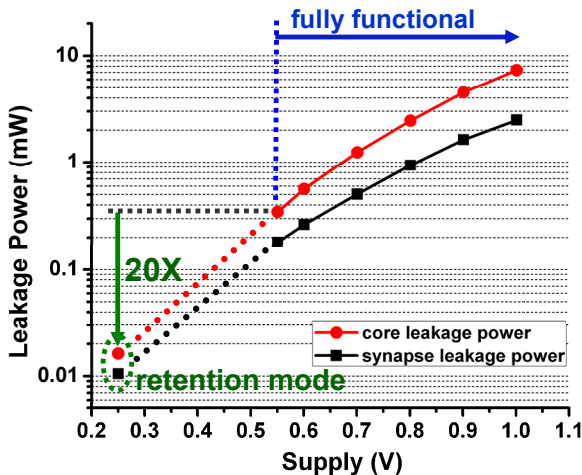


Fig. 7. Voltage scaling and power-gating of the low-leakage variant chip. ‘core’ includes 256 neurons, FSM, priority encoder, and clock distribution. ‘synapse’ includes 64K synapses and according peripheral circuits.

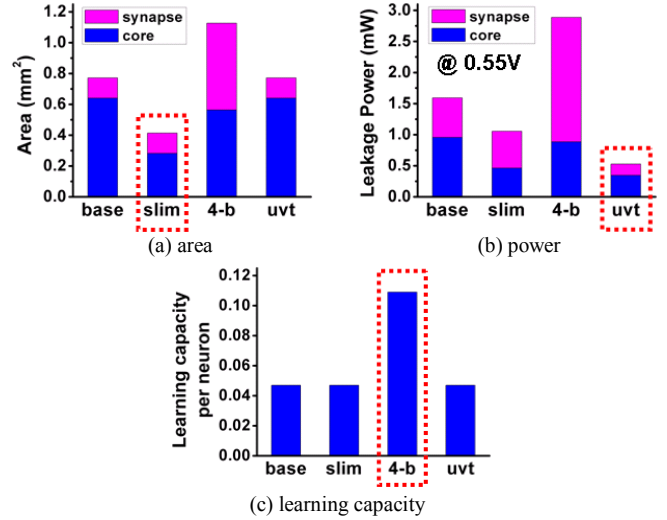


Fig. 8. Density, power, and learning performance (in Hopfield-like network) trade-off of 4 variants.

VI. CONCLUSION

In this paper, we demonstrated a highly configurable neuromorphic chip with integrated learning for use in pattern classification, recognition, and associative memory tasks. Through the use of digital neuron circuits and a novel transposable crossbar SRAM array, this basic building block addresses the computation, memory, and communication requirements for large-scale networks of spiking neurons and is scalable to advanced technology nodes. Future systems will build on this base to enable ubiquitously deployable ultra-dense, ultra-low power brain-like cognitive computers.

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